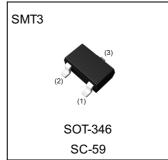


High-current Gain Medium Power Transistor (20V, 500mA)

Parameter	Value
V_{CEO}	20V
IC	0.5A

Outline



Features

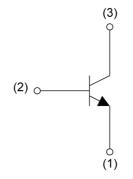
- 1)High DC current gain
- 2)High emitter-base voltage.

V_{EBO}=12V

3)Low V_{CE(sat)}.

 $V_{CE(sat)}$ =180mV(Typ.) (I_C/I_B =500mA/20mA)

•Inner circuit



- (1) Emitter
- (2) Base
- (3) Collector

Application

LOW FREQUENCY AMPLIFIER, MUTING, DC-DC CONVERTER

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SD2114K	SMT3	2928	T146	180	8	3000	BB

● Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	V_{CBO}	25	V
Collector-emitter voltage	V _{CEO}	20	V
Emitter-base voltage	V _{EBO}	12	V
Calle ster arrange	I _C	0.5	Α
Collector current	I _{CP} *1	1.0	Α
Power dissipation	P _D *2	200	mW
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

● Electrical characteristics (T_a = 25°C)

Doromotor	Cumbal	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Collector-base breakdown voltage	BV _{CBO}	I _C = 10μA	25	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	20	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = 10μA	12	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 20V	-	-	500	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 10V	-	-	500	nA
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = 500mA, I _B = 20mA	-	180	400	mV
DC current gain	h _{FE}	$V_{CE} = 3V, I_{C} = 10mA$	820	1	2700	-
Transition frequency	f _T	V _{CE} = 10V, I _E = -50mA, f = 100MHz	-	350	-	MHz
Output capacitance	C_ob	V _{CB} = 10V, I _E = 0A, f = 1MHz	-	8.0	-	pF
On resistance	R _{on}	V _i = 100mVrms, I _B = 1mA, f = 1kHz (See test circuit)	-	0.8	-	Ω

hFE values are calssified as follows:

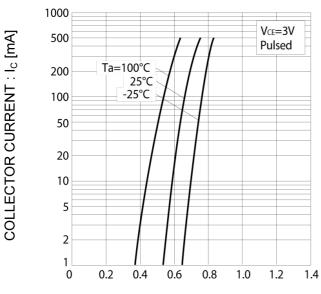
rank	V	W	-	-	-
h _{FE}	820-1800	1200-2700	-	-	-

^{*1} Pw=10ms Single Pulse

^{*2} Each terminal mounted on a reference land.

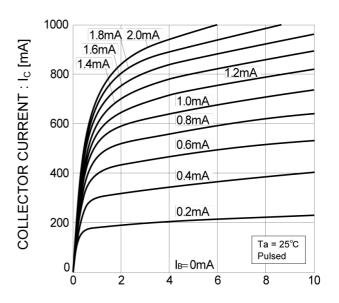
● Electrical characteristic curves(T_a = 25°C)

Fig.1 Ground Emitter Propagation Characteristics



BASE TO EMITTER VOLTAGE : VBE [V]

Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: V_{CE} [V]

Fig.3 DC Current Gain vs. Collector Current (I)

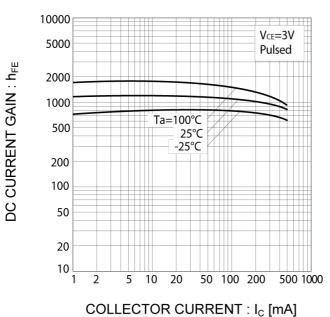
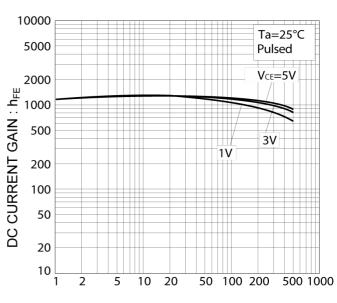


Fig.4 DC Current Gain vs. Collector Current (II)



COLLECTOR CURRENT : I_C [mA]

● Electrical characteristic curves(T_a = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

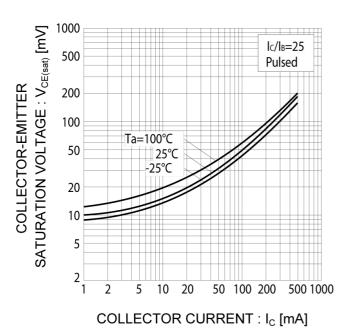


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

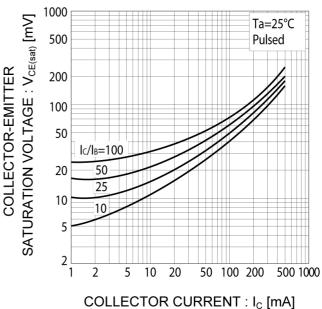


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

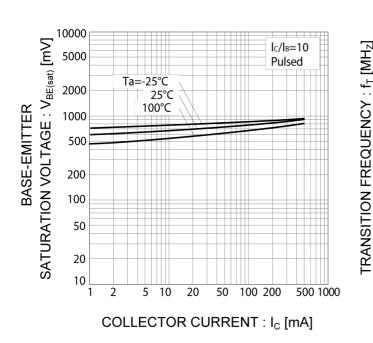
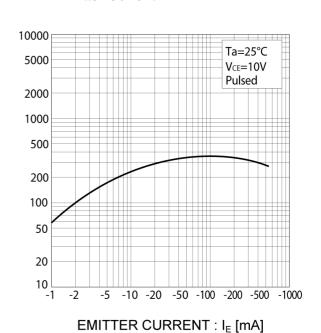


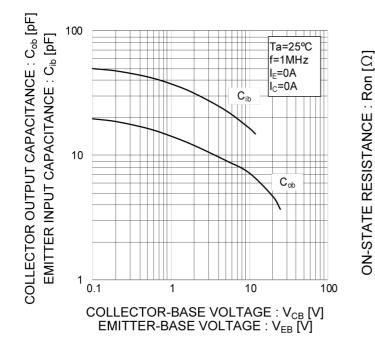
Fig.8 Gain Bandwidth Product vs.
Emitter Current



● Electrical characteristic curves(T_a = 25°C)

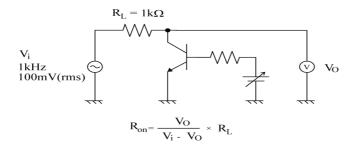
Fig.9 Emitter Input Capacitance vs.
Emitter-Base Voltage
Collector Output Capacitance vs.
Collector-Base Voltage

Fig.10 'ON' Resistance vs. Base Current



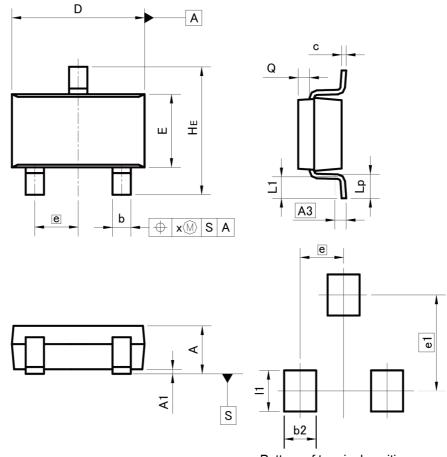
100 Ta= 25°C 50 f=1MHz Vi=100mV (rms) $R_L=1k\Omega$ 20 10 5 2 0.5 0.2 0.1 0.01 0.02 0.05 0.1 0.2 5 10 BASE CURRENT : I_B [mA]

Ron MEASUREMENT CIRCUIT



Dimensions

SMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

D.114	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.00	1.30	0.039	0.051	
A1	0.00	0.10	0.000	0.004	
A3	0.:	0.25		10	
b	0.35	0.50	0.014	0.020	
С	0.09	0.25	0.004	0.010	
D	2.80	3.00	0.110	0.118	
E	1.50	1.80	0.059	0.071	
е	0.95		0.037		
HE	2.60	3.00	0.102	0.118	
L1	0.30	0.60	0.012	0.024	
Lp	0.40	0.70	0.016	0.028	
Q	0.20	0.30	0.008	0.012	
х	_	0.10	-	0.004	
У	_	0.10	_	0.004	

DIM	MILIM	ETERS	INCHES		
	MIN	MAX	MIN	MAX	
b2	_	0.60	-	0.024	
e1	2.10		0.083		
l1	_	0.90	_	0.035	

Dimension in mm/inches



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